

Vishay Siliconix

RoHS

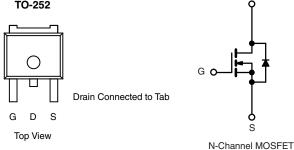
COMPLIANT

HALOGEN FREE

Automotive N-Channel 50 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	50			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.011			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.015			
I _D (A)	50			
Configuration	Single			
	D			

TO-252



FEATURES

- TrenchFET[®] Power MOSFET
- · Package with Low Thermal Resistance
- 100 % $R_{\rm q}$ and UIS Tested
- AEC-Q101 Qualified^d
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

ORDERING INFORMATION	
Package	TO-252
Lead (Pb)-free and Halogen-free	SQD50N05-11L-GE3

ABSOLUTE MAXIMUM RATINGS ($T_c = 25 \degree C$, unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	50	М
Gate-Source Voltage		V _{GS}	± 20	V
Continuous Drain Current	T _C = 25 °C ^a	1	50	
	T _C = 125 °C	- I _D	32	
Continuous Source Current (Diode Conduction) ^a		I _S	50	А
Pulsed Drain Current ^b		I _{DM}	200	
Single Pulse Avalanche Energy	L = 0.1 mH	I _{AS}	45	
Single Pulse Avalanche Current	L = 0.1 MH	E _{AS}	101	mJ
Maximum Power Dissipation ^b	T _C = 25 °C	Р	75	W
	T _C = 125 °C	PD	25	vv
Operating Junction and Storage Temperature	T _J , T _{stg}	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	60	°C/W
Junction-to-Case (Drain)		R _{thJC}	2.0	C/W

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$		50	-	-	v	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	V _{DS} = V _{GS} , I _D = 250 μA		2.0	2.5	v	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 50 V	-	-	1.0		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 50 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 50 V, T _J = 175 °C	-	-	250		
On-State Drain Currenta	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	50	-	-	А	
		V _{GS} = 10 V	I _D = 45 A	-	0.009	0.011	Ω	
Durin Course On Otata Desistance		$V_{GS} = 10 V$	I _D = 45 A, T _J = 125 °C	-	-	0.020		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 45 A, T _J = 175 °C	-	-	0.024		
		$V_{GS} = 4.5 V$	I _D = 20 A	-	-	0.015		
Forward Transconductanceb	9 _{fs}	V _{DS}	V _{DS} = 15 V, I _D = 30 A		58	-	S	
Dynamic ^b	·							
Input Capacitance	C _{iss}			-	1685	2106	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	345	430		
Reverse Transfer Capacitance	C _{rss}	1		-	144	180		
Total Gate Charge ^c	Qg			-	34.6	52	nC	
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 25 \text{ V}, I_D = 43 \text{ A}$	-	5.5	9		
Gate-Drain Charge ^c	Q _{gd}			-	9.1	14		
Gate Resistance	Rg	f = 1 MHz		1.3	2.6	3.9	Ω	
Turn-On Delay Time ^c	t _{d(on)}			-	8.5	13		
Rise Time ^c	tr	$\label{eq:V_DD} \begin{array}{l} V_{\text{DD}} = 25 \text{ V}, \ R_{\text{L}} = 0.6 \ \Omega \\ I_{\text{D}} \cong 43 \text{ A}, \ V_{\text{GEN}} = 10 \text{ V}, \ R_{g} = 1 \ \Omega \end{array}$		-	11.5	18	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	22.5	34		
Fall Time ^c	t _f			-	7.5	12		
Source-Drain Diode Ratings and Char	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	200	А	
Forward Voltage	V _{SD}	I _F = 45 A, V _{GS} = 0 V		-	0.95	1.5	V	

Notes

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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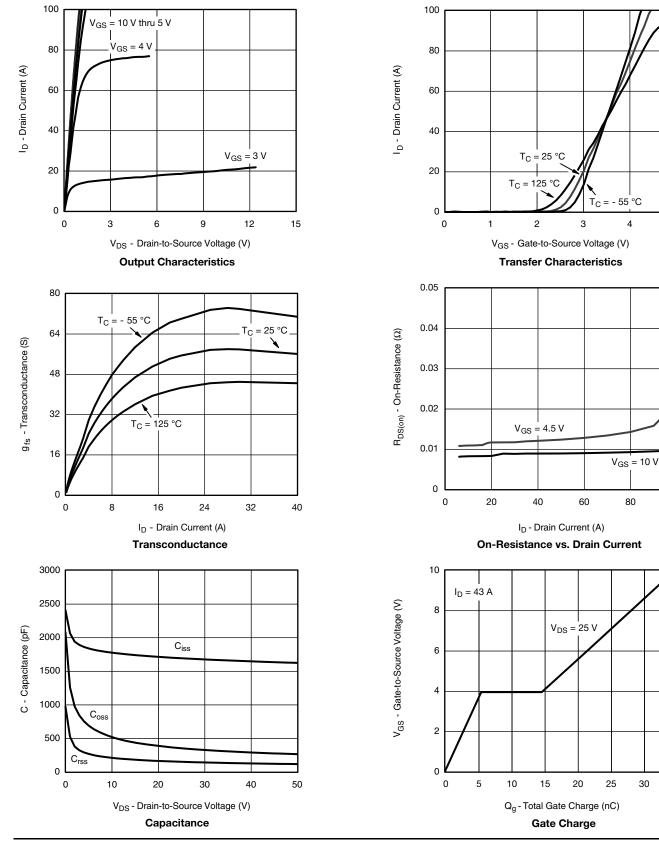


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100

35

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



S12-2673-Rev. C, 05-Nov-12

3

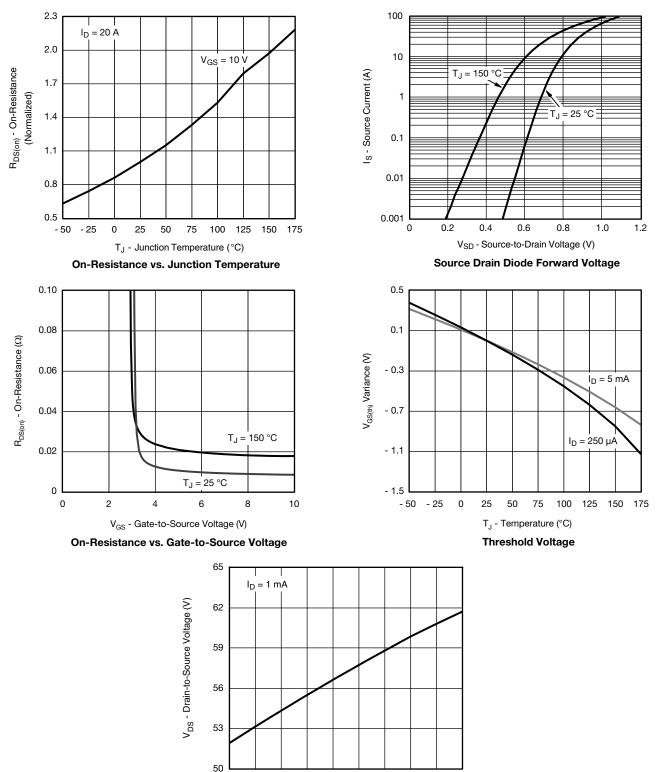
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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



T_J - Junction Temperature (°C)

50 75 100

25

- 25

0

- 50

Drain Source Breakdown vs. Junction Temperature

125

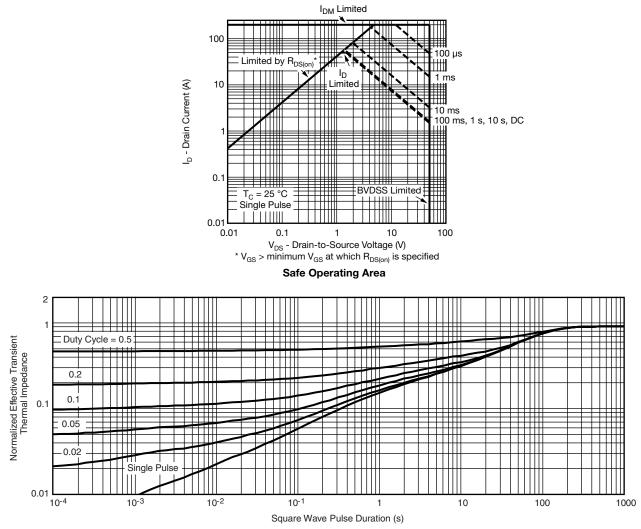
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)

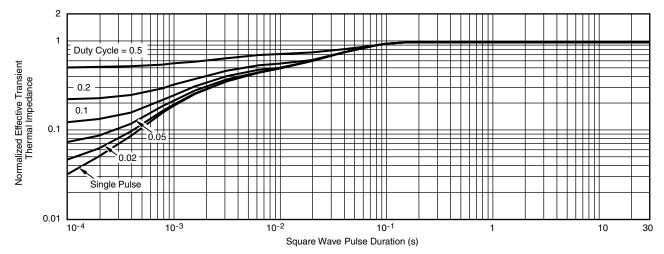


Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

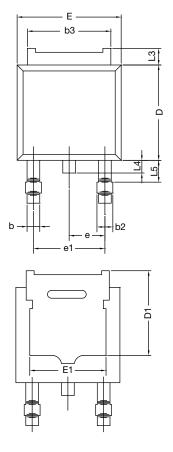
- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

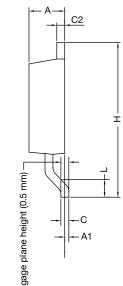
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72168.





TO-252AA CASE OUTLINE



	MILLIN	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	5.21	-	0.205	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090	BSC	
e1	4.56	4.56 BSC		BSC	
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	
	ECN: X12-0247-Rev. M, 24-Dec-12 DWG: 5347				

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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